## Data Sheet

## FEATURES

Dual, current-controlled output current sources with 4 input channels
TTL-selectable output
Stable on-chip oscillators with independent frequency and amplitude control
TTL- or LVDS-selectable write channel enables negative logic Independent TTL oscillator enables positive logic
170 mA minimum output current for the read channel
510 mA minimum output current for Write Channel 1
330 mA minimum output current for Write Channel 2
165 mA minimum output current for Write Channel 3
950 mA typical total output current
Typical rise time/fall time of 0.8 ns
Low power consumption
Single 5 V power supply ( $\mathbf{\pm 1 0 \%}$ )

## APPLICATIONS

DVD-R, DVD+R, DVD-RW, DVD+RW, DVD-RAM
supercombo drives
Magneto-optical (MO) drives
Laser diode current switching
OTDR laser drivers

## GENERAL DESCRIPTION

The AD9665 is a laser diode driver for high performance CD-RW and DVD recordable drives. It includes four channels for four different optical power levels: the read channel generates a continuous output power level, whereas Channel 1, Channel 2, and Channel 3 can be used as write channels that can be controlled with an LVDS or TTL interface. The WxDIS and $\overline{\text { RDIS }}$ pins are active low logic. The OSCEN pin is controlled by an active high TTL signal. All active channels are summed at the output where Write Channel 1 can contribute at least 325 mA output current, and Write Channel 2 and Write Channel 3 can contribute at least 250 mA and 150 mA , respectively. The level of the output current is set by an external resistor, which converts this voltage into a current at the WxSET pin.

An on-chip oscillator is provided to allow output current modulation and to reduce laser-mode hopping. Four external resistors permit the setting of two distinct values for the frequency and swing of the oscillator. The oscillator can output up to 100 mA p-p of current (push-pull oscillator) with a frequency range of 200 MHz to 500 MHz .

## TABLE OF CONTENTS

Features ..... 1
Applications. .....  1
General Description .....  1
Functional Block Diagram .....  1
Revision History ..... 2
Specifications ..... 3
Absolute Maximum Ratings .....  5
ESD Caution .....  5
Typical Performance Characteristics .....  6
Logic Table ..... 8
Applications Information ..... 9
REVISION HISTORY
9/15-Rev. E to Rev. F
Changed N/C Pin to DNC PinThroughout
Changes to Applications Section and Figure 2 ..... 1
Changes to Figure 3 to Figure 6 and Figure 8 ..... 6
Change to Figure 12 ..... 7
Change to Table 5 ..... 13
Board Layout .....  9
Temperature Considerations .....  9
Shutdown Supply Current Variation ..... 11
Evaluation Board ..... 12
Schematic ..... 12
Operation ..... 13
Pin Descriptions ..... 13
Outline Dimensions ..... 14
Ordering Guide ..... 14

## SPECIFICATIONS

At $25^{\circ} \mathrm{C}, \mathrm{V}_{\mathrm{DD}}=5 \mathrm{~V}, \mathrm{ENABLE}=1, \mathrm{OSCEN}=0, \mathrm{~F}_{\mathrm{ADJ}}=6.81 \mathrm{k} \Omega, \mathrm{A}_{\mathrm{ADJ}}=5.76 \mathrm{k} \Omega, \mathrm{V}_{\text {out }}=2.5 \mathrm{~V}$, Iout $=50 \mathrm{~mA}$ (Read), $\overline{\mathrm{RDIS}}=0$, unless otherwise specified.

Table 1.

| Parameter | Conditions | Min | Typ | Max | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: |
| LASER AMPLIFIER |  |  |  |  |  |
| Output Current Read Channel | Output is sourcing, $\mathrm{l}_{\mathrm{N}}=2 \mathrm{~mA}$ | 170 | 190 |  | mA |
|  | Output is sourcing, $\mathrm{V}_{\text {OUT }}=3.5 \mathrm{~V}, \mathrm{l}_{\mathrm{N}}=2 \mathrm{~mA}$ | 150 | 170 |  | mA |
| Output Current Write Channel 1 | Output is sourcing, $\mathrm{l}_{\mathbb{N}}=2 \mathrm{~mA}$ | 510 | 540 |  | mA |
|  | Output is sourcing, $\mathrm{V}_{\text {OUT }}=3.5 \mathrm{~V}, \mathrm{l}_{\mathrm{N}}=2 \mathrm{~mA}$ | 450 | 480 |  | $m A$ |
| Output Current Write Channel 2 | Output is sourcing, $\mathrm{l}_{\mathbb{N}}=2 \mathrm{~mA}$ | 330 | 360 |  | $m A$ |
|  | Output is sourcing, $\mathrm{V}_{\text {OUT }}=3.5 \mathrm{~V}, \mathrm{l}_{\mathrm{IN}}=2 \mathrm{~mA}$ | 290 | 320 |  | mA |
| Output Current Write Channel 3 | Output is sourcing, $\mathrm{l}_{\mathrm{N}}=2 \mathrm{~mA}$ | 165 | 185 |  | $m A$ |
|  | Output is sourcing, $\mathrm{V}_{\text {OUT }}=3.5 \mathrm{~V}, \mathrm{l}_{\mathrm{IN}}=2 \mathrm{~mA}$ | 145 | 165 |  | $m A$ |
| Total Output Current (See Figure 11) | All channels sourcing, $\mathrm{l}_{\mathrm{N}}=1.45 \mathrm{~mA}$ | 875 | 950 |  | mA |
|  | All channels sourcing, $\mathrm{V}_{\text {OUT }}=3.5 \mathrm{~V}, \mathrm{I}_{\text {IN }}=1.45 \mathrm{~mA}$ | 775 | 850 |  | mA |
| Output Current Linearity Error | Read channel or Write Channel $3^{1}$ | -1.5 | $\pm 0.4$ | +1.5 | \% |
|  | Write Channel $1^{2}$ or Write Channel $2^{3}$ | -1.0 | $\pm 0.2$ | +1.0 | \% |
|  | Write Channel 1, $\mathrm{V}_{\text {OUt }}=3.5 \mathrm{~V}, \mathrm{l}_{\mathrm{I}}=2 \mathrm{~mA}^{4}$ | -15 | -9 |  | \% |
| Best-Fit Current Gain | Read channel ${ }^{1}$ | 85 | 105 | 115 | $\mathrm{mA} / \mathrm{mA}$ |
|  | Write Channel $1^{2}$ | 265 | 300 | 335 | $\mathrm{mA} / \mathrm{mA}$ |
|  | Write Channel $2^{3}$ | 165 | 200 | 225 | $\mathrm{mA} / \mathrm{mA}$ |
|  | Write Channel $3^{1}$ | 80 | 100 | 110 | $\mathrm{mA} / \mathrm{mA}$ |
| Best-Fit Current Offset | Read channel or Write Channel $3^{1}$ | -7 | -2 | +4 | mA |
|  | Write Channel $1^{2}$ | -17 | -3 | +11 | mA |
|  | Write Channel $2^{3}$ | -11 | -1 | +8 | mA |
| IIN Input Impedance ( $\mathrm{RiN}_{\mathrm{IN}}$ ), All Channels lout Current Output Noise | $\mathrm{R}_{\text {IN }}$ to GND, lout $=0 \mathrm{~mA}$ | 140 | 200 | 260 |  |
|  | $\mathrm{f}=300 \mathrm{MHz}$ |  | 100 |  | $\mathrm{pA} / \sqrt{ } \mathrm{Hz}$ |
| lout Supply Sensitivity, (PSRR) Write Mode | $V_{D D}=5 \mathrm{~V} \pm 10 \%$ |  | 3.5 |  | \%/V |
|  | lout $=100 \mathrm{~mA}, 50 \mathrm{~mA}$ read channel, 50 mA any write channel, $\mathrm{V}_{\mathrm{DD}}=5 \mathrm{~V} \pm 10 \%$ |  | 3.5 |  | \%/V |
| lour Temperature Sensitivity, Read Mode lout Temperature Sensitivity, Write Mode |  |  | 175 |  | ppm $/{ }^{\circ} \mathrm{C}$ |
|  | lour $=100 \mathrm{~mA}$ ( 50 mA read channel, 50 mA Write Channel 1) |  | 150 |  | ppm $/{ }^{\circ} \mathrm{C}$ |
|  | lout $=100 \mathrm{~mA}$ ( 50 mA read channel, 50 mA Write Channel 2) |  | 390 |  | ppm $/{ }^{\circ} \mathrm{C}$ |
|  | lout $=100 \mathrm{~mA}$ ( 50 mA read channel, 50 mA Write Channel 3) |  | 350 |  | ppm $/{ }^{\circ} \mathrm{C}$ |
| LASER AMPLIFIER AC SPECIFICATIONS |  |  |  |  |  |
| Write Rise Time | lout $=50 \mathrm{~mA}$ (read channel), 150 mA (Write Channel 1) ${ }^{5}$ |  | 0.75 | 0.95 | ns |
|  | $\begin{aligned} & \text { lout }=65 \mathrm{~mA} \text { (read channel), } 375 \mathrm{~mA} \text { (Write Channel 1), } \\ & \mathrm{V}_{\mathrm{DD}}=5 \mathrm{~V}, \mathrm{~V}_{\text {OUT }}=3.5 \mathrm{~V}^{6} \end{aligned}$ |  | 0.8 | 1.3 | ns |
|  | lout $=50 \mathrm{~mA}$ (read channel), 100 mA (Write Channel 2) ${ }^{5}$ |  | 0.6 | 0.8 | ns |
|  | lout $=50 \mathrm{~mA}$ (read channel), 50 mA (Write Channel 3) ${ }^{5}$ |  | 0.55 | 0.75 | ns |
| Write Fall Time | lout $=50 \mathrm{~mA}$ (read channel), 150 mA (Write Channel 1) ${ }^{7}$ |  | 0.55 | 0.75 | ns |
|  | $\begin{aligned} & \text { lout }=65 \mathrm{~mA} \text { (read channel), } 375 \mathrm{~mA} \text { (Write Channel 1), } \\ & \mathrm{V}_{\mathrm{DD}}=5 \mathrm{~V}, \mathrm{~V}_{\text {OUT }}=3.5 \mathrm{~V}^{8} \end{aligned}$ |  | 0.4 | 0.6 | ns |
|  | lout $=50 \mathrm{~mA}$ (read channel), 100 mA (Write Channel 2) ${ }^{7}$ |  | 0.55 | 0.75 | ns |
|  | lout $=50 \mathrm{~mA}$ (read channel), 50 mA (Write Channel 3) ${ }^{7}$ |  | 0.45 | 0.65 | ns |
| lout ON Propagation Delay (LVDS Mode) | Logic at $50 \%$ of final value to lout at $50 \%$ of final value |  | 5.2 |  | ns |
| lour OFF Propagation Delay (LVDS Mode) | Logic at $50 \%$ of final value to lout at $50 \%$ of final value |  | 6.3 |  | ns |
| Disable Time | ENABLE $50 \% \mathrm{H}$-L to lout at $50 \%$ of final value |  | 3.8 |  | ns |
| Enable Time | ENABLE $50 \%$ L-H to lout at $50 \%$ of final value |  | 5.5 |  | ns |
| Output Switching Time | OUTSEL $50 \%$ to lout at $50 \%$ of final value |  | 3 |  | ns |
| OSCILLATOR SPECIFICATIONS |  |  |  |  |  |
| Oscillator Frequency | OSCEN $=1$ | 280 | 315 | 340 | MHz |
| Oscillator Amplitude | OSCEN = 1 |  | 50 |  | mA p-p |
| Oscillator Temperature Coefficient | Oscillator amplitude, OSCEN = 1 |  | 60 |  | $\mu \mathrm{Ap-p} /{ }^{\circ} \mathrm{C}$ |
|  | Oscillator frequency, OSCEN = 1 |  | 195 |  | kHz/ ${ }^{\circ} \mathrm{C}$ |


| Parameter | Conditions |  |  |  |  |  | Min | Typ | Max | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Disable Time Oscillator | OSCEN 50\% H-L to lout at 50\% of final value, OSCEN = 1 OSCEN $50 \%$ L-H to lout at $50 \%$ of final value, OSCEN $=1$ |  |  |  |  |  |  | 2 |  | ns |
| Enable Time Oscillator |  |  |  |  |  |  |  | 4 |  | ns |
| LOGIC SPECIFICATIONS INS = 1 (LVDS Mode) |  |  |  |  |  |  |  |  |  |  |
|  |  |  |  |  |  |  |  |  |  |  |  |  |  |  |  |  |
| Minimum Differential Input Voltage | Magnitude |  |  |  |  |  | 100 |  |  | mV |
| Maximum Differential Input Voltage | Magnitude |  |  |  |  |  |  |  | 600 | mV |
| Valid Input Voltage | Relative to GND |  |  |  |  |  | 0 |  | 2.4 | V |
| OUTEN |  |  |  |  |  |  |  |  |  |  |
| Logic HI Threshold | Temperature stabilized |  |  |  |  |  | 2.0 |  |  | V |
| Logic LO Threshold | Temperature stabilized |  |  |  |  |  |  |  | 0.8 | V |
| SUPPLY CURRENT ${ }^{9}$ INS = 1 (LVDS Mode) | ENABLE | OSCEN | $\overline{\text { RDIS }}$ | W1DIS ${ }^{10}$ | W2DIS ${ }^{10}$ | W3DIS ${ }^{10}$ |  |  |  |  |
|  |  |  |  |  |  |  |  |  |  |  |
| Power Down | 0 | 0 | 1 | 1 | 1 | 1 |  | 8.6 |  | mA |
| Inputs Disabled, Read Enabled | 1 | 0 | 0 | 1 | 1 | 1 |  | 26 |  | $m A$ |
| Inputs Disabled, Oscillator Enabled | 1 | 1 | 1 | 1 | 1 | 1 |  | 46 |  | mA |
| Read Mode, Oscillator Enabled ${ }^{11}$ $\text { lout }=50 \mathrm{~mA}$ | 1 | 1 | 0 | 1 | 1 | 1 |  | 54 |  | mA |
| Write Mode ${ }^{11}$ | 1 | 0 | 1 | 0 | 0 | 0 |  | 49 |  | mA |
| lout $=150 \mathrm{~mA}$ ( 50 mA Write Channel 1, Write Channel 2, Write Channel 3) |  |  |  |  |  |  |  |  |  |  |
| INS = 0 (TTL Mode) |  |  |  |  |  |  |  |  |  |  |
| Power-Down | 0 | 0 | 1 | 1 | 1 | 1 |  | 9.5 |  | mA |
| Inputs Disabled, Read Enabled | 1 | 0 | 0 | 1 | 1 | 1 |  | 23 |  | mA |
| Inputs Disabled, Oscillator Enabled | 1 | 1 | 1 | 1 | 1 | 1 |  | 43 |  | mA |
| Read Mode, Oscillator Enabled ${ }^{11}$ | 1 | 1 | 0 | 1 | 1 | 1 |  | 51 |  | mA |
| lout $=50 \mathrm{~mA}$ |  |  |  |  |  |  |  |  |  |  |
| Write Mode ${ }^{11}$ | 1 | 0 | 1 | 0 | 0 | 0 |  | 43 |  | mA |
| lour $=150 \mathrm{~mA}$ ( 50 mA Write Channel 1, Write Channel 2, Write Channel 3) |  |  |  |  |  |  |  |  |  |  |
| OPERATING CONDITIONS <br> Supply Voltage Range <br> Operating Temperature Range |  |  |  |  |  |  |  |  |  |  |
|  |  |  |  |  |  |  | $\begin{aligned} & 4.5 \\ & -25 \end{aligned}$ |  | 5.5 | V |
|  |  |  |  |  |  |  |  | +85 | ${ }^{\circ} \mathrm{C}$ |

${ }^{1}$ Output linearity, offset current, and gain are calculated using the best-fit method at $30 \mathrm{~mA}, 60 \mathrm{~mA}$, and 90 mA . The transfer function is lout $=\left(l_{\mathrm{IN}} \times\right.$ GAIN $)+$ los.
${ }^{2}$ Output linearity, offset current, and gain are calculated using the best-fit method at $90 \mathrm{~mA}, 120 \mathrm{~mA}$, and 150 mA . The transfer function is $l_{\text {out }}=\left(l_{\mathbb{N}} \times G A I N\right)+l_{\text {os }}$.
${ }^{3}$ Output linearity, offset current, and gain are calculated using the best-fit method at $60 \mathrm{~mA}, 90 \mathrm{~mA}$, and 120 mA . The transfer function is $l_{\text {lout }}=\left(I_{\mathrm{IN}} \times \mathrm{GAIN}\right)+\mathrm{l}_{\mathrm{os}}$.
${ }^{4}$ Output linearity is calculated using the best-fit method, which is calculated at $90 \mathrm{~mA}, 120 \mathrm{~mA}$, and 150 mA , extrapolated to $\mathrm{l}_{\mathrm{N}}=2 \mathrm{~mA}$.
${ }^{5}$ Measured electrically from $10 \%$ to $90 \%$ of final value. Sharp Diode-GH06550B2B (see Figure 14).
${ }^{6}$ Measured electrically from $10 \%$ to $90 \%$ of final value. Mitsubishi Diode-ML101J26. $R_{L}=0.66 \Omega$ (see Figure 14).
${ }^{7}$ Measured electrically from $90 \%$ to $10 \%$ of final value. Sharp Diode-GH06550B2B (see Figure 14).
${ }^{8}$ Measured electrically from $90 \%$ to $10 \%$ of final value. Mitsubishi Diode-ML101J26. $R_{L}=0.66 \Omega$ (see Figure 14).
${ }^{9}$ See the Shutdown Supply Current Variation section for more information.
${ }^{10}$ WxDIS $=0$ means channel is off regardless of mode: TTL or LVDS (see Table 3). WxDIS = 1 means channel is on regardless of mode: TTL or LVDS (see Table 3).
${ }^{11}$ The value specified does not include the output current.

## ABSOLUTE MAXIMUM RATINGS

Table 2.

| Parameter | Range |
| :--- | :--- |
| Supply Voltage (+V VD$)$ |  |
| $\quad$ Pins $10,11,17,23,32$ | 6 V |
| Input Pins | 2.2 mA |
| $\quad$ Pins $12,13,14,15$ | -0.8 V to $+\mathrm{V}_{\mathrm{DD}}$ |
| Pins 1,2,5,6,7,8,9,16,24,29,30 |  |
| Internal Power Dissipation ${ }^{1}$ | 2 W |
| $\quad 5 \mathrm{~mm} \times 5 \mathrm{~mm}, 32$-Lead, Pad-Up LFCSP |  |
| Operating Temperature Range | $-25^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$ |
| Storage Temperature Range | $-65^{\circ} \mathrm{C}$ to $+150^{\circ} \mathrm{C}$ |

${ }^{1}$ Power dissipation is specified on semistandard 4-layer board.

Stresses at or above those listed under Absolute Maximum Ratings may cause permanent damage to the product. This is a stress rating only; functional operation of the product at these or any other conditions above those indicated in the operational section of this specification is not implied. Operation beyond the maximum operating conditions for extended periods may affect product reliability.

## ESD CAUTION

|  | ESD (electrostatic discharge) sensitive device. <br> Charged devices and circuit boards can discharge <br> without detection. Although this product features <br> patented or proprietary protection circuitry, damage <br> may occur on devices subjected to high energy ESD. <br> Therefore, proper ESD precautions should be taken to <br> avoid performance degradation or loss of functionality. |
| :--- | :--- |

## AD9665

## TYPICAL PERFORMANCE CHARACTERISTICS



Figure 3. Oscillator Frequency vs. FADر


Figure 4. Oscillator Amplitude vs. Frequency


Figure 5. Iout Current Noise vs. Frequency


Figure 6. Oscillator Amplitude vs. AADJ


Figure 7. Oscillator Amplitude vs. Iout-dC


Figure 8. Oscillator Distortion vs. Frequency


Figure 9. Oscillator Amplitude vs. Temperature


Figure 10. Output Current vs. Input Current for Each Channel, V $\mathrm{V}_{\text {out }}=2.5 \mathrm{~V}$


Figure 11. Total lout vs. IN


Figure 12. Oscillator Frequency vs. Temperature


Figure 13. Output Current vs. Input Current for Each Channel, Vout $=3.5 \mathrm{~V}$


Figure 14. Electrical LVDS Pulse Response Schematic

## AD9665

## LOGIC TABLE

Table 3.

| ENABLE | OUTSEL | OSCEN | INS | $\overline{\text { RDIS }}$ | W1DIS | W1DISN | W2DIS | W2DISN | W3DIS | W3DISN | osc | LD1 | LD2 |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| L | x | x | x | x | x | x | x | x | x | x | x | OFF | OFF |
| H | L | L | L | L | H | x | H | x | H | x | OFF | OFF | $\mathrm{I}_{\text {RSET }} \times 100 \mathrm{~mA} / \mathrm{mA}$ |
| H | L | H | L | L | H | x | H | x | H | x | ON | OFF | $\begin{aligned} & \mathrm{I}_{\mathrm{RSET}} \times 100 \mathrm{~mA} / \mathrm{mA}+ \\ & \mathrm{l}_{\mathrm{SC}}\left(\mathrm{~F}_{\mathrm{FDJ2}}+\mathrm{A}_{\text {ADJ2 }}\right) \\ & \hline \end{aligned}$ |
| H | L | H | L | H | L | x | H | $x$ | H | x | ON | OFF | $\begin{gathered} 1_{\text {W1SET }} \times \\ 300 \mathrm{~mA} / \mathrm{mA}+ \\ \mathrm{l}_{\mathrm{OSc}}\left(\mathrm{~F}_{\mathrm{ADJ2}}+\mathrm{A}_{\mathrm{ADJ} 2}\right) \\ \hline \end{gathered}$ |
| H | L | H | L | H | H | x | L | x | H | x | ON | OFF | $\begin{aligned} & \mathrm{I}_{\mathrm{W} 2 \mathrm{SET}} \times 200 \mathrm{~mA} / \mathrm{mA}+ \\ & \mathrm{l}_{\mathrm{OSc}}\left(\mathrm{~F}_{\mathrm{ADJ2}}+\mathrm{A}_{\mathrm{ADJ} 2}\right) \end{aligned}$ |
| H | L | H | L | H | H | x | H | x | L | $x$ | ON | OFF | $\begin{aligned} & I_{\text {W3SET }} \times 100 \mathrm{~mA} / \mathrm{mA}+ \\ & \mathrm{I}_{\mathrm{OSC}}\left(\mathrm{~F}_{\text {ADJ2 }}+\mathrm{A}_{\text {ADJ } 2}\right) \end{aligned}$ |
| H | L | H | L | H | H | x | H | x | H | x | ON | OFF | $\begin{gathered} \mathrm{I}_{\mathrm{OSC}}\left(\mathrm{~F}_{\mathrm{ADJ2}}+\mathrm{A}_{\mathrm{ADJ} 2}\right) \\ \text { (NOTTRECOMMENDED) } \end{gathered}$ |
| H | L | L | H | L | H | L | H | L | H | L | OFF | OFF | $\mathrm{I}_{\text {RSET }} \times 100 \mathrm{~mA} / \mathrm{mA}$ |
| H | L | H | H | L | H | L | H | L | H | L | ON | OFF | $\begin{aligned} & \mathrm{I}_{\mathrm{RSET}} \times 100 \mathrm{~mA} / \mathrm{mA}+ \\ & \mathrm{I}_{\mathrm{Sc}}\left(\mathrm{~F}_{\text {ADJ2 }}+\mathrm{A}_{\text {ADJ } 2}\right) \end{aligned}$ |
| H | L | H | H | H | L | H | H | L | H | L | ON | OFF | l $_{\text {W1SET }} \times$ $300 \mathrm{~mA} / \mathrm{mA}+$ $\mathrm{I}_{\mathrm{OSC}}\left(\mathrm{F}_{\text {ADJ2 }}+\mathrm{A}_{\text {ADJ2 }}\right)$ |
| H | L | H | H | H | H | L | L | H | H | L | ON | OFF | $\begin{aligned} & I_{\text {W2SET }} \times 200 \mathrm{~mA} / \mathrm{mA}+ \\ & \mathrm{I}_{\mathrm{OSC}}\left(\mathrm{~F}_{\mathrm{ADJ2}}+\mathrm{A}_{\mathrm{ADJ} 2}\right) \end{aligned}$ |
| H | L | H | H | H | H | L | H | L | L | H | ON | OFF | $\begin{aligned} & I_{\text {W3SET }} \times 100 \mathrm{~mA} / \mathrm{mA}+ \\ & \operatorname{loscc}_{\text {OS }}\left(F_{\text {ADJ2 }}+A_{\text {ADJ }}\right) \end{aligned}$ |
| H | L | H | H | H | H | x | H | $x$ | H | $x$ | ON | OFF | $\begin{gathered} \mathrm{I}_{\mathrm{OSC}}\left(\mathrm{~F}_{\mathrm{ADJ2}}+\mathrm{A}_{\text {ADJJ2 }}\right) \\ \text { (NOT RECOMMENDED) } \end{gathered}$ |
| H | H | L | L | L | H | x | H | x | H | x | OFF | $\mathrm{I}_{\text {RSET }} \times 100 \mathrm{~mA} / \mathrm{mA}$ | OFF |
| H | H | H | L | L | H | x | H | x | H | x | ON | $\begin{aligned} & \mathrm{I}_{\mathrm{RSET}} \times 100 \mathrm{~mA} / \mathrm{mA}+ \\ & \mathrm{I}_{\mathrm{SCC}}\left(\mathrm{~F}_{\text {ADJ1 }}+\mathrm{A}_{\text {ADJ1 }}\right) \end{aligned}$ | OFF |
| H | H | H | L | H | L | x | H | x | H | x | ON | $\mathrm{I}_{\mathrm{W} 1 \mathrm{SET}} \times 300 \mathrm{~mA} / \mathrm{mA}+$ $\operatorname{losc}\left(F_{A D J 1}+A_{A D J 1}\right)$ | OFF |
| H | H | H | L | H | H | x | L | x | H | x | ON |  | OFF |
| H | H | H | L | H | H | x | H | $x$ | L | x | ON | $I_{\text {W3SET }} \times 100 \mathrm{~mA} / \mathrm{mA}+$ <br> $\operatorname{losc}^{\log }\left(F_{A D 11}+A_{A D J 1}\right)$ | OFF |
| H | H | H | L | H | H | x | H | x | H | x | ON | $\begin{gathered} \mathrm{I}_{\mathrm{OSC}}\left(\mathrm{~F}_{\mathrm{ADJ1}}+\mathrm{A}_{\text {ADJI }}\right) \\ \text { (NOT RECOMMENDED) }) \end{gathered}$ | OFF |
| H | H | L | H | L | H | L | H | L | H | L | OFF | $\mathrm{I}_{\text {RSET }} \times 100 \mathrm{~mA} / \mathrm{mA}$ | OFF |
| H | H | H | H | L | H | L | H | L | H | L | ON | $\begin{aligned} & I_{\text {RSET }} \times 100 \mathrm{~mA} / \mathrm{mA}+ \\ & \left.\operatorname{los}+F_{\text {ADJ1 }}+\mathrm{A}_{\text {ADJ1 }}\right) \end{aligned}$ | OFF |
| H | H | H | H | H | L | H | H | L | H | L | ON | $I_{\text {W1SET }} \times 300 \mathrm{~mA} / \mathrm{mA}+$ $\operatorname{losc}\left(F_{A D J 1}+A_{A D J 1}\right)$ | OFF |
| H | H | H | H | H | H | L | L | H | H | L | ON | $\begin{aligned} & \mathrm{I}_{\mathrm{W} 2 \mathrm{SET}} \times 200 \mathrm{~mA} / \mathrm{mA}+ \\ & \operatorname{losc}_{\mathrm{OSC}}\left(\mathrm{~F}_{\mathrm{ADJ1}}+\mathrm{A}_{\mathrm{ADJ1}}\right) \end{aligned}$ | OFF |
| H | H | H | H | H | H | L | H | L | L | H | ON | $I_{\text {W3SET }} \times 100 \mathrm{~mA} / \mathrm{mA}+$ <br> $\operatorname{losc}\left(F_{A D J 1}+A_{A D J 1}\right)$ | OFF |
| H | H | H | H | H | H | L | H | L | H | L | ON | $\begin{gathered} \mathrm{I}_{\mathrm{OSC}}\left(\mathrm{~F}_{\mathrm{ADJ1}}+\mathrm{A}_{\text {ADJ1 }}\right) \\ \text { (NOT RECOMMENDED) } \end{gathered}$ | OFF |
| $\begin{aligned} & \text { OUTSEL } \\ & \text { H = LD1 OUTPUT } \\ & \text { L = LD2 OUTPUT } \end{aligned}$ |  |  | $\begin{aligned} & \text { INS } \\ & \mathrm{H}=\mathrm{LVDS} \\ & \mathrm{~L}=\mathrm{TTL} \end{aligned}$ |  | $\begin{aligned} & \text { OSCEN } \\ & \text { H = OSCILLATOR ON } \\ & \text { L OSCILLATOR OFF } \end{aligned}$ |  |  | TTL <br> USE LVDS + INPUT |  |  |  |  |  |

## APPLICATIONS INFORMATION

The AD9665 uses the current at one or more of its four inputs, RSET, W1SET, W2SET, and W3SET, and generates an output current proportional to the sum of the input currents. The read channel has a typical gain of $105 \mathrm{~mA} / \mathrm{mA}$, Write Channel 1 has a typical gain of $300 \mathrm{~mA} / \mathrm{mA}$, Write Channel 2 has a typical gain of $200 \mathrm{~mA} / \mathrm{mA}$, and Write Channel 3 has a typical gain of $100 \mathrm{~mA} / \mathrm{mA}$. The input impedance of all the channels is typically $200 \Omega$. In most cases, a voltage output DAC can be used to drive these channels. In this case, a series resistance should be placed between each of the DAC channels and the respective input on the AD9665. These resistances should be selected to scale the desired maximum output current for each channel with an appropriate voltage from the DAC without excessively loading it.

## BOARD LAYOUT

Due to the fast rise and fall time ( $<1 \mathrm{~ns}$ ) required for the operation of high speed drives, trace lengths carrying high speed signals, such as $\overline{\text { RDIS }}$, W1DIS, W2DIS, and W3DIS, and the output current should be kept as short as possible to minimize series inductance. A decoupling capacitor should be located near each $V_{D D}$ pin, and the ground return for the cathode of the laser diode should be kept as short as possible.

An S11 measurement of a piece of flexible printed circuit board (FPC) can show the inductance associated with that section of the FPC. In Table 4, an S11 measurement of two different pieces of a $19 \mathrm{~mm}(0.75 \mathrm{in})$ FPC was taken. The first piece is a single layer of an FPC with 0.5 ounce copper and 25.4 micron ( 1 mil ) thick Kapton ${ }^{\oplus}$ and coverlay. The second piece is an FPC with 2 layers of 0.5 ounce copper and 25.4 micron ( 1 mil) thick Kapton and coverlay.

Table 4. Inductance of FPC

| $\mathbf{S 1 1}$ | $\mathbf{L}, \mathbf{n H}$ @ $\mathbf{1 0} \mathbf{~ M H z}$ | $\mathbf{L}, \mathbf{n H} @ \mathbf{3 0 0} \mathbf{~ M H z}$ |
| :--- | :--- | :--- |
| Single-layer FPC | 8.8 | 8.5 |
| Double-layer FPC | 4.3 | 4.2 |

As indicated by the measurement results, using two layers of copper in an FPC can reduce inductance by over $50 \%$. Using the basic circuit equation

$$
V=L \frac{d i}{d t}
$$

it can be seen that increasing the amplitude of a current step increases the voltage drop across the inductor. For example, on the single-layer FPC, a 200 mA pulse with a rise time of 1 ns generates a voltage drop of 1.86 V , assuming an additional 0.5 nH of inductance due to the laser diode itself. Increase this current to 250 mA , and the voltage drop is greater than 2.3 V .

Add this to the $\sim 2 \mathrm{~V}$ of operating voltage that is required for the laser diode, and voltage headroom can become a problem if operating on a 5 V supply. Because the di/dt term seems to be a system requirement, L is the only contributor that can be changed when trying to reduce the voltage drop. Decreasing the inductance of the FPC can be done by either making the trace wider or by making it shorter. Because the distance from the laser diode driver (LDD) to the laser diode is fixed, using a wider trace is the only option. This can be accomplished by changing from a single-layer FPC design to a double-layer FPC design. This additional layer allows the full width of the FPC from the LDD to the laser diode to be used for the drive current, while the bottom layer can be used entirely for the return path (see Figure 15).


Figure 15. Single-Layer and Double-Layer Flexible Printed Circuit Boards

## TEMPERATURE CONSIDERATIONS

The AD9665 is available in a 32 -lead LFCSP with an exposed heat pad on top of the package. Using a 4-layer JEDEC standard test board, the $\theta_{J A}$ of this package was determined without any external heat sink attached to the exposed pad. This board is made of FR4, is 1.60 mm thick, and consists of four copper layers. The two internal layers are solid copper ( $1 \mathrm{oz} / \mathrm{in}^{2}$ or 0.35 mm thick). The two surface layers (containing the component and back side traces) use $2 \mathrm{oz} / \mathrm{in}^{2}$ ( 0.70 mm thick) of copper. This method of construction yields a $\theta_{\mathrm{IA}}$ for the AD9665 of approximately $110^{\circ} \mathrm{C} / \mathrm{W}$. An integrated circuit dissipating 500 mW and packaged in an LFCSP, while operating in an ambient environment of $85^{\circ} \mathrm{C}$, would have an internal junction temperature of approximately $140^{\circ} \mathrm{C}$.

$$
85^{\circ} \mathrm{C}+0.5 \mathrm{~W} \times 110^{\circ} \mathrm{C} / \mathrm{W}=140^{\circ} \mathrm{C}
$$

This junction temperature is within the maximum recommended operating junction temperature of $150^{\circ} \mathrm{C}$. This can be improved by attaching an external heat sink to the exposed heat pad of the package. Of course, this is not a realistic method for mounting a laser diode driver in an optical storage device.

In an actual application, the laser diode driver would most likely be mounted to a flexible circuit board. The $\theta_{\mathrm{JA}}$ of a system
is highly dependent on the board layout, material, and heat sink. The user must consider these conditions carefully.
Some of the circuitry of the AD9665 can be used to monitor the internal junction temperature.

The AD9665 uses a combination of diodes and transistors to protect it from electrostatic discharge (ESD). All input pins have a diode between them and ground, with the anode connected to ground and the cathode connected to the particular input pin. The base-emitter junction of a PNP transistor is used for ESD protection for each pin to $V_{D D}$. The collector is electrically connected to the substrate of the die (see Figure 16). The baseemitter junction of this transistor can be used to monitor the internal die temperature of the IC.
Using a 10 V source at the enable pin to forward-bias the baseemitter junction and a $1 \mathrm{M} \Omega$ resistor to limit the current, a 2-point measurement can be used to calculate the junction temperature of the IC. Because the enable pin (ENABLE) needs to be high for normal operation, the AD9665 can be operated normally with the 10 V applied through the $1 \mathrm{M} \Omega$ resistor. For this experiment, V1 and V2 were measured between the ENABLE pin (Pin 16) and the closest $\mathrm{V}_{\mathrm{DD}}$ pin (Pin 17).


Figure 16. Junction Temperature Measurement Circuit
The most important aspect of measuring junction temperature on the AD9665 is that only one variable in the system is changed at a time. In this case, the only variable is the amount of power being dissipated by the AD9665. Therefore, the ambient temperature should be held constant. For example, to measure the junction temperature of the AD9665 while operating at $60^{\circ} \mathrm{C}$ ambient, the ambient temperature must be held constant for both the initial measurement, V1, and the final measurement, V2. This is true because of the relationship between temperature and $\mathrm{V}_{\text {be. }}$. For the process with which the AD9665 is fabricated, the change in $\mathrm{V}_{\text {BE }}\left(\Delta \mathrm{V}_{\mathrm{BE}}\right)$ is related to the die temperature by $-1.9 \mathrm{mV} /{ }^{\circ} \mathrm{C}$ (note the negative coefficient). Therefore, die temperature is directly related to ambient temperature and the power dissipated.

While the power to the AD9665 is disconnected, the AD9665 should be allowed to reach thermal equilibrium (at the desired ambient temperature). With all channels turned off such that Iout $=0 \mathrm{~mA}$, measure V1 as shown in Figure 16 (note the polarity).
The second point of the 2-point measurement is obtained when the AD9665 is operated under load, for example, while driving a laser. Before taking the measurement, the AD9665 must be allowed adequate time to reach a thermal equilibrium.
As seen in Figure 16, the AD9665 has a finite parasitic resistance (Rs) between $V_{D D}$ (Pin 17) and the base of the PNP transistor. This resistance is typically $120 \mathrm{~m} \Omega$. Because the goal of the experiment is to measure $\Delta \mathrm{V}_{\mathrm{BE}}$ of the transistor, the voltage drop across this resistance must be taken into account to get an accurate representation of the actual $\Delta \mathrm{V}_{\text {BE }}$. This voltage drop varies depending on the output current of the AD9665 operating under load. Therefore, the actual supply current ( $\mathrm{I}_{\mathrm{DD}}$ ) must be measured for each measurement.

$$
V_{D R O P}=I_{D D} \times R s
$$

So the resulting $\Delta \mathrm{V}_{\mathrm{BE}}$ can be found as

$$
\Delta V_{B E}=\left(V 2+V_{D R O P 2}\right)-\left(V 1+V_{D R O P P_{1}}\right)
$$

For increasing temperature, this result should be negative.
From $\Delta V_{B E}$, the final junction temperature is determined by

$$
T_{J}=T_{A}+\left|\frac{\Delta V_{B E}}{-1.9 \mathrm{mV} /{ }^{\circ} \mathrm{C}}\right|
$$

From the resulting temperature rise in addition to the measured power dissipation, the thermal resistance from the junction to ambient can be calculated as

$$
\begin{aligned}
& P_{D}=V_{D D} \times I_{D D}-V_{L O A D} \times I_{L O A D} \\
& \theta_{I A}=\frac{T_{J}-T_{A}}{P_{D}}
\end{aligned}
$$

## SHUTDOWN SUPPLY CURRENT VARIATION

The AD9665 defaults to TTL input mode when the ENABLE pin is tied low (ENABLE $=0$ ), regardless of the position of the INS pin. Because of this, there can be additional supply current due to the applied voltage on the read, write, or OSCEN enable pins, the cause of which is an inverter located on the TTL input ENABLE pins (see Figure 17).


Figure 17. Inverter Circuit

Voltages close to GND or VDD are not sufficient to turn on both transistors. However, as voltages vary from these extremes, significant current can flow. Figure 18 shows how the powerdown current varies with voltage applied on the read, write, or OSCEN enable pins.
Therefore, to ensure the lowest possible shutdown current, the read, write, and OSCEN voltages should be tied to either 0 V or 5 V .


Figure 18. Read and Write TTL Enable Voltage vs. Supply Current

## AD9665

## EVALUATION BOARD

## SCHEMATIC



Figure 19. AD9665ACPZ-32 Evaluation Board Schematic

## OPERATION

## PIN DESCRIPTIONS

Table 5.

| Pin No. | Mnemonic | Description |
| :---: | :---: | :---: |
| 1 | W3DISN | Negative Enable for Write Channel 3 (LVDS Mode Only). |
| 2 | W3DIS | Positive Enable for Write Channel 3 (LVDS Mode), Enable (TTL Mode). |
| 3,4 | GND | Ground. |
| 5 | W2DISN | Negative Enable for Write Channel 2 (LVDS Mode Only). |
| 6 | W2DIS | Positive Enable for Write Channel 2 (LVDS Mode), Enable (TTL Mode). |
| 7 | $\overline{\text { W1DISN }}$ | Negative Enable for Write Channel 1 (LVDS Mode Only). |
| 8 | W1DIS | Positive Enable for Write Channel 1 (LVDS Mode), Enable (TTL Mode). |
| 9 | $\overline{\mathrm{RDIS}}$ | Enable for R Channel (TTL Only). |
| 10 | VDD | 5 V Supply and DC Logic Level for RDIS and ENABLE. |
| 11 | $V_{D D}$ | 5 V Supply and DC Logic Level for RDIS and ENABLE. |
| 12 | W3SET | Input for Write Channel 3 ( $\mathrm{R}_{\text {IN }}=200 \Omega$ ). |
| 13 | W2SET | Input for Write Channel 2 ( $\mathrm{R}_{\mathbf{N}}=200 \Omega$ ). |
| 14 | W1SET | Input for Write Channel 1 (RIN=200 $)^{\text {) }}$ |
| 15 | RSET | Input for Read Channel ( $\mathrm{RiN}=200 \Omega$ ). |
| 16 | ENABLE | Chip Enable-Active High. |
| 17 | $V_{\text {DD }}$ | Output Stage Supply, 5 V . |
| 18, 19 | LD2 | Output 2. |
| 20 | GND | Ground. |
| 21, 22 | LD1 | Output 1. |
| 23 | VDD | Output Stage Supply, 5 V . |
| 24 | INS | Logic mode select ( $0=$ TTL, $1=$ LVDS $)$. |
| 25 | $\mathrm{A}_{\text {AD/2 }}$ | Amplitude Resistor Set for Oscillator 2. |
| 26 | $\mathrm{A}_{\text {ADJ1 }}$ | Amplitude Resistor Set for Oscillator 1. |
| 27 | $\mathrm{F}_{\text {ADJ2 }}$ | Frequency Resistor Set for Oscillator 2. |
| 28 | $\mathrm{F}_{\text {AD } 1}$ | Frequency Resistor Set for Oscillator 1. |
| 29 | OUTSEL | Output Select (0 LD2, $1=$ LD1). |
| 30 | OSCEN | Oscillator Enable—Active High. |
| 31 | DNC | Do not connect. Leave this pin floating with no external connection. |
| 32 | $V_{\text {DD }}$ | 5 V Supply and DC Logic Level for OSCEN. |
| N/A | EPAD | Exposed Pad. When pulling a high current, attach heat sink on the exposed pad. |

The logic signals, WxDIS, $\overline{\text { WxDISN }}, \overline{\text { RDIS, ENABLE, INS, }}$ OUTSEL, and OSCEN, can be driven with pulsed sources or can be set to a steady state level with jumpers. For steady state operation, the logic levels for the WxDIS and WxDISN pins are set with voltages applied to the VDPOS and VDNEG pins on the evaluation board. For LVDS mode (INS =1), VDPOS and VDNEG should be at a level greater than 50 mV and less than $2.45 \mathrm{~V}(0.050 \mathrm{~V}<\mathrm{VDPOS}<2.45 \mathrm{~V}$ and $0.05 \mathrm{~V}<\mathrm{VDNEG}<2.45 \mathrm{~V})$, with the differential voltage greater than 100 mV and less than 600 mV . For TTL operation (INS $=0$ ), VDPOS should be greater than 2.5 V and VDNEG should be less than 0.8 V . Under TTL operation, it may be convenient to put VDPOS at 5 V and VDNEG at 0 V . The pin labeled 5 V is the logic level for INS and OUTSEL.

The $V_{\text {DD }}$ pins are connected together in the IC and can be connected to the same external supply. Although they are all connected internally, there must be a direct connection to each of these pins through their vector pins externally, which are also labeled $V_{\text {DD }}$.

A jumper set to the right side of a 3-lead connection applies the VDPOS voltage to the applicable pin on the IC. A jumper set to the left side of a 3-lead connection applies the VDNEG voltage.

Evaluation boards are shipped with $100 \Omega$ termination resistors across the LVDS inputs and without $50 \Omega$ resistors on the other logic traces. Resistors R5 and R8 can be connected between ground and the cathodes of Diode 1 and Diode 2, respectively. To monitor diode current with an oscilloscope, a $3.1 \Omega$ resistor can be placed in each of these positions. The series $46.4 \Omega$ resistors at R4 and R9 present a $50 \Omega$ impedance to measurement equipment. This results in the oscilloscope displaying the diode current with a conversion factor of $1.558 \mathrm{mV} / \mathrm{mA}$. If this capability is not desired, $0 \Omega$ resistors can be installed in the R5 and R8 positions.

## AD9665

## OUTLINE DIMENSIONS


*COMPLIANT TO JEDEC STANDARDS MO-220 WITH EXCEPTION TO PADDLE ORIENTATION. FOR PROPER CONNECTION OF THE EXPOSED PAD, REFER TO THE PIN DESCRIPTIONS SECTION OF THIS DATA SHEET.

Figure 20. 32-Lead, Pad-Up, Lead Frame Chip Scale Package [LFCSP_VQ]
$5 \mathrm{~mm} \times 5 \mathrm{~mm}$ Body, Very Thin Quad
(CP-32-1)
Dimensions shown in millimeters

ORDERING GUIDE

| Model $^{1}$ | Temperature Range | Package Description | Package Option |
| :--- | :--- | :--- | :--- |
| AD9665ACPZ-REEL | $-25^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$ | 32 -Lead, Pad-Up, Lead Frame Chip Scale Package [LFCSP_VQ] | CP-32-1 |
| AD9665ACPZ-REEL7 | $-25^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$ | 32 -Lead, Pad-Up, Lead Frame Chip Scale Package [LFCSP_VQ] | CP-32-1 |

[^0]$\square$
Data Sheet
NOTES

## NOTES

LifeElectronics
Живое партнерство

Компания «Life Electronics» занимается поставками электронных компонентов импортного и отечественного производства от производителей и со складов крупных дистрибьюторов Европы, Америки и Азии.

С конца 2013 года компания активно расширяет линейку поставок компонентов по направлению коаксиальный кабель, кварцевые генераторы и конденсаторы (керамические, пленочные, электролитические), за счёт заключения дистрибьюторских договоров

Мы предлагаем:

- Конкурентоспособные цены и скидки постоянным клиентам.
- Специальные условия для постоянных клиентов.
- Подбор аналогов.
- Поставку компонентов в любых объемах, удовлетворяющих вашим потребностям.
- Приемлемые сроки поставки, возможна ускоренная поставка.
- Доставку товара в любую точку России и стран СНГ.
- Комплексную поставку.
- Работу по проектам и поставку образцов.
- Формирование склада под заказчика.
- Сертификаты соответствия на поставляемую продукцию (по желанию клиента).
- Тестирование поставляемой продукции.
- Поставку компонентов, требующих военную и космическую приемку.
- Входной контроль качества.
- Наличие сертификата ISO.

В составе нашей компании организован Конструкторский отдел, призванный помогать разработчикам, и инженерам.

Конструкторский отдел помогает осуществить:

- Регистрацию проекта у производителя компонентов.
- Техническую поддержку проекта.
- Защиту от снятия компонента с производства.
- Оценку стоимости проекта по компонентам.
- Изготовление тестовой платы монтаж и пусконаладочные работы.


> Тел: +7 (812) 3364304 (многоканальный)
> Email: org@lifeelectronics.ru


[^0]:    ${ }^{1} Z=$ RoHS Compliant Part.

